



ELECTRONICS, INC.
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NTE5332 & NTE5334 Silicon Bridge Rectifier, 1A

Features:

- Glass Passivated Chip Junctions
- Surge Overload Rating: 50A (Peak)
- Ideal for Printed Circuit Board
- High Temperature Soldering Guaranteed: +285°C/10 seconds at 5 lbs., (2.3kg) tension

Maximum Ratings and Electrical Characteristics: (T_A = +25°C unless otherwise specified, 60Hz, Resistive or Inductive Load.)

Maximum Recurrent Peak Reverse Voltage, V _{RRM}	
NTE5332	600V
NTE5334	1000V
Maximum RMS, V _{RMS}	
NTE5332	420V
NTE5334	700V
Maximum DC Blocking Voltage, V _{DC}	
NTE5332	600V
NTE5334	1000V
Maximum Average Forward Output Rectified Current (T _A = +40°C), I _{O(AV)}	1A
Peak Forward Surge Current (Single Sine-Wave Superimposed on Rated Load), I _{FSM}	50A
Rating for Fusing (t < 8.35ms), I ² t	10A ² s
Maximum Instantaneous Forward Voltage Drop (Per element at 1A), V _F	1.2V
Maximum Reverse Current at Rated DC Blocking Voltage Per Element, I _R	
T _A = +25°C	10µA
T _A = +125°C	500µA
Typical Junction Capacitance Per Element (Note 1), C _J	25pf
Typical thermal Resistance (Note 2), R _{θJA}	+40°C/W
Operating Junction Temperature Range, T _J	-65° to +150°C
Storage Temperature Range, T _{stg}	-65° to +150°C

Note 1. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts.

Note 2. Thermal Resistance from Junction to Ambient mounted on P.C. Board with 0.5" x 0.5" (13mm x 13mm) Copper Pads.



